TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

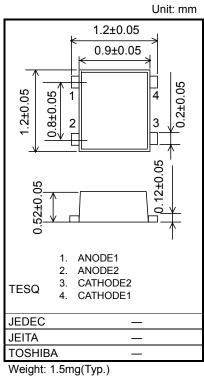
# HN2S03T

High Speed Switching Application

- Two independent diodes are mounted on Thin Extreme Super Mini Quad package that are suitable for higher mounting densities.
- Low forward voltage : V<sub>F (3)</sub> = 0.50V (typ.)
- Low reverse current : I<sub>R</sub>= 0.5µA (max)
- Small total capacitance : C<sub>T</sub> = 3.9pF (typ.)

#### Maximum Ratings (Q1, Q2 Common, Ta = 25°C)

| Characteristic                 | Symbol           | Rating  | Unit |
|--------------------------------|------------------|---------|------|
| Maximum (peak) reverse Voltage | V <sub>RM</sub>  | 25      | V    |
| Reverse voltage                | V <sub>R</sub>   | 20      | V    |
| Maximum (peak) forward current | I <sub>FM</sub>  | 100 *   | mA   |
| Average forward current        | Ι <sub>Ο</sub>   | 50 *    | mA   |
| Surge current (10ms)           | I <sub>FSM</sub> | 1 *     | А    |
| Power dissipation              | Р                | 70 **   | mW   |
| Junction temperature           | Tj               | 125     | °C   |
| Storage temperature range      | T <sub>stg</sub> | -55~125 | °C   |
| Operating temperature range    | T <sub>opr</sub> | -40~100 | °C   |



vveight: 1.5mg(

\* : Unit rating. Total rating = Unit rating x 1.5

\*\*: Total rating

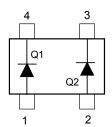
### Electrical Characteristics (Q1, Q2 Common, Ta = 25°C)

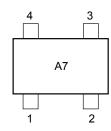
| Characteristic    | Symbol             | Test<br>Circuit | Test Condition                           | Min | Тур. | Max  | Unit |
|-------------------|--------------------|-----------------|--|-----|------|------|------|
| Forward voltage   | V <sub>F (1)</sub> | _               | I <sub>F</sub> = 1mA                     | _   | 0.33 | _    |      |
|                   | V <sub>F (2)</sub> | _               | I <sub>F</sub> = 5mA                     | _   | 0.38 | _    | V    |
|                   | V <sub>F (3)</sub> | _               | I <sub>F</sub> = 50mA                    | _   | 0.50 | 0.55 |      |
| Reverse current   | I <sub>R</sub>     | —               | V <sub>R</sub> = 20V                     | —   | —    | 0.5  | μA   |
| Total capacitance | CT                 | _               | V <sub>R</sub> = 0, f = 1MH <sub>z</sub> |     | 3.9  |      | pF   |

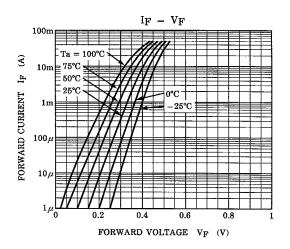
TOSHIBA

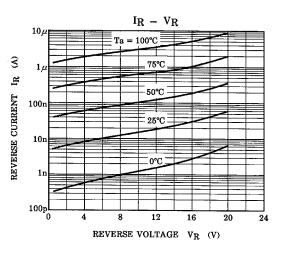
# Pin Assignment (Top View)

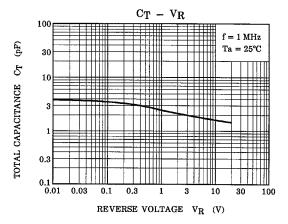
Marking



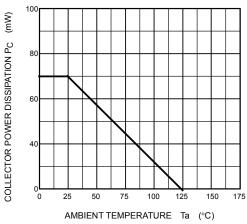












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